0 = 31 - 6 / CRN

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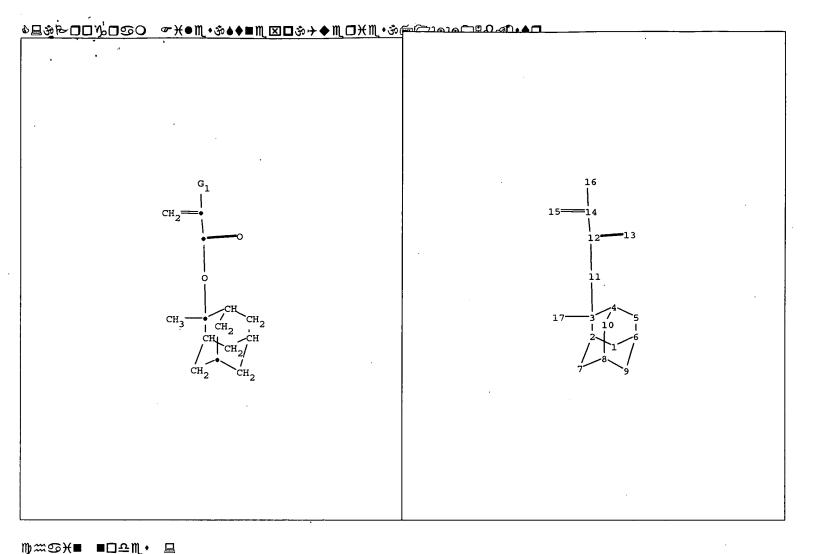
10 8 - 31 - 6 / CRN

$$\begin{array}{c} \text{CF}_3 \\ \text{CH} \\ \text{CH} \\ \text{CH} \\ \text{CH}_2 \\ \text{CF}_3 \\ \text{CF}_3 \\ \end{array}$$

SEARCH: CA REG. File STructure securch. Polymers in claim 4.

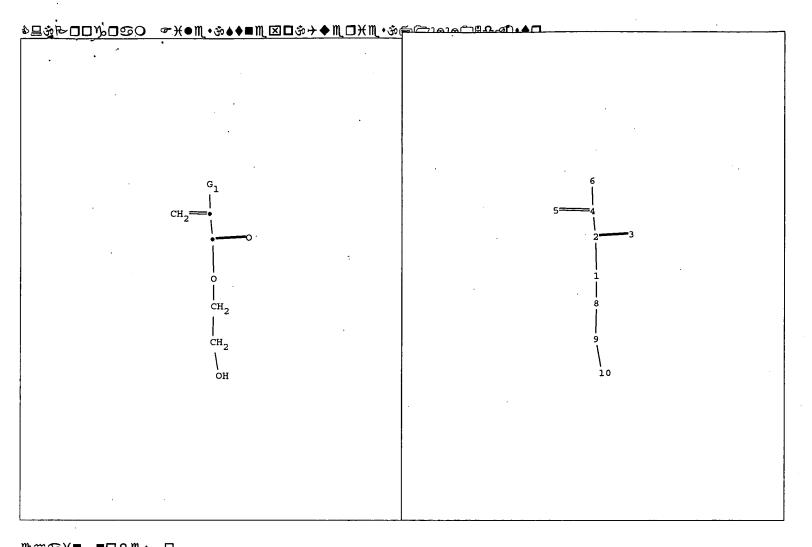
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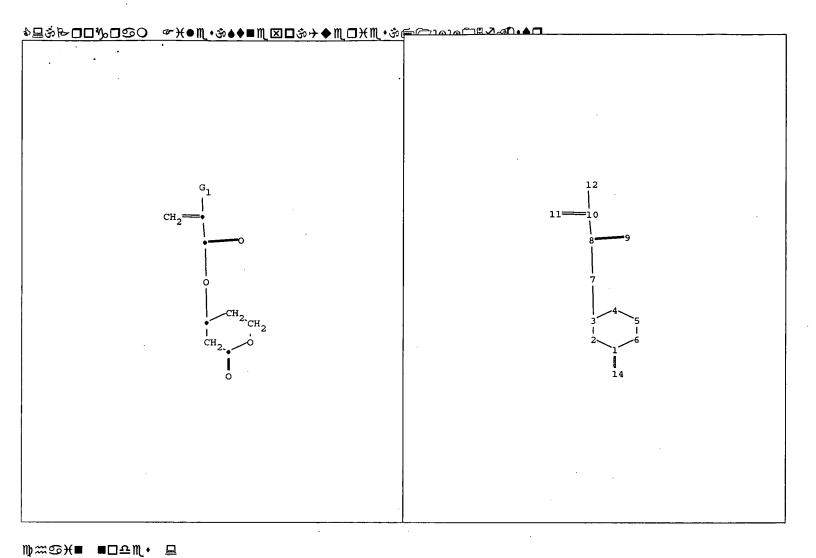


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30 ANSWER 1 OF 1 CAPLUS COPYRIGHT 2005 ACS on STN

AN 2005:98956 CAPLUS

DN 142:207614

TI Photoresist polymer and photoresist composition containing the same

IN Lee, Geun Su; Bok, Cheol Kyu; Moon, Seung Chan; Shin, Ki Soo; Kim, Jae Hyun; Kim, Jung Woo; Lee, Sang Hyang; Kang, Jae Hyun

PA S. Korea

SO U.S. Pat. Appl. Publ., 17 pp.

CODEN: USXXCO

DT Patent

LA English

FAN. CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
ΡΙ	US 2005026070	A1	20050203	US 2008-719905	20031121
PRAI	KR 2003-52337	A	20030729		

AB Photoresist polymers and photoresist compns. are disclosed. A photoresist polymer is represented by I (X1-4 = CH2, CH2CH2, S; R1,2 = H, CH3, CF3; R3 = C1-20 alkyl, etc.; R4 = C1-20 hydroxyalkyl, etc.; R5 = H, C1-20 hydroxyalkyl, etc.; m = 0-2; and n = 0, 1). The photoresist compns. have excellent etching resistance, thermal resistance and adhesive property, and high affinity to an developing solution, thereby improving LER (line edge roughness).

IT 836623-60-0P 836623-61-1P

RL: SPN (Synthetic preparation); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)

(photoresist polymer for photoresist composition)

RN 836623-60-0 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 1,1-dimethylethyl ester, polymer with  $\alpha,\alpha$ -bis(trifluoromethyl)bicyclo[2.2.1]hept-5-ene-2-ethanol, 2,5-furandione and 2-hydroxyethyl 2-methyl-2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 196314-61-1 CMF C11 H12 F6 O Myrappl.

CM 2

$$^{\rm H_2C}$$
 O  $^{\rm H_2}$   $^{\rm H_2}$   $^{\rm H_2}$   $^{\rm H_2}$   $^{\rm H_2}$   $^{\rm H_2}$   $^{\rm H_2}$  OH

CRN 585-07-9 CMF C8 H14 O2

CM 4

CRN 108-31-6 CMF C4 H2 O3

RN 836623-61-1 CAPLUS

CN Bicyclo[2.2.1]hept-5-ene-2-carboxylic acid, 1,1-dimethylethyl ester, polymer with  $\alpha,\alpha$ -bis(trifluoromethyl)bicyclo[2.2.1]hept-5-ene-2-ethanol, 1,1-dimethylethyl 2-methyl-2-propenoate, 2,5-furandione and 2-hydroxyethyl 2-methyl-2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 196314-61-1 CMF C11 H12 F6 O

CM 2

CRN 154970-45-3 CMF C12 H18 O2

CM 3

CRN 585-07-9 CMF C8 H14 O2

CM 5

CRN 108-31-6 CMF C4 H2 O3

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L32 ANSWER 1 OF 1 CAPLUS COPYRIGHT 2005 ACS on STN

AN 2005:98956 CAPLUS

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SO U.S. Pat. Appl. Publ., 17 pp.

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LA English

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IT 836623-58-6P 836623-59-7P

RL: SPN (Synthetic preparation); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)

(photoresist polymer for photoresist composition)

RN 836623-58-6 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 2-hydroxyethyl ester, polymer with  $\alpha, \alpha$ -bis(trifluoromethyl)bicyclo[2.2.1]hept-5-ene-2-ethanol, 2,5-furandione and 2-methyltricyclo[3.3.1.13,7]dec-2-yl 2-methyl-2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 196314-61-1 CMF C11 H12 F6 O

CM 2

CRN 177080-67-0 CMF C15 H22 O2

CRN 868-77-9 CMF C6 H10 O3

CM 4

CRN 108-31-6 CMF C4 H2 O3

RN 836623-59-7 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 2-hydroxyethyl ester, polymer with
bicyclo[2.2.1]hept-2-ene, α,α-bis(trifluoromethyl)bicyclo[2.2.
1]hept-5-ene-2-ethanol, 2,5-furandione and 2-methyltricyclo[3.3.1.13,7]dec2-yl 2-methyl-2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 196314-61-1 CMF C11 H12 F6 O

CM 2

CRN 177080-67-0 CMF C15 H22 O2

CM 3

CRN 868-77-9

L12 ANSWER 1 OF 1 CAPLUS COPYRIGHT 2005 ACS on STN

AN 2005:98956 CAPLUS

DN 142:207614

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PA S. Korea

SO U.S. Pat. Appl. Publ., 17 pp.

CODEN: USXXCO

DT Patent

LA English

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IT 836623-58-6P 836623-59-7P

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(photoresist polymer for photoresist composition)

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CM 2

CRN 177080-67-0 CMF C15 H22 O2

CRN 868-77-9 CMF C6 H10 O3

CM 4

CRN 108-31-6 CMF C4 H2 O3

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CRN 196314-61-1 CMF C11 H12 F6 O

CM 2

CRN 177080-67-0 CMF C15 H22 O2

CM 3

CRN 868-77-9

CMF C6 H10 O3

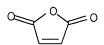
CM 4

CRN 498-66-8 CMF C7 H10



CM !

CRN 108-31-6 CMF C4 H2 O3



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L16 ANSWER 1 OF 1 CAPLUS COPYRIGHT 2005 ACS on STN

AN 2005:98956 CAPLUS

DN 142:207614

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SO U.S. Pat. Appl. Publ., 17 pp.

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DT Patent

LA English

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CRN 585-07-9 CMF C8 H14 O2

CM 4

CRN 108-31-6 CMF C4 H2 O3

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CM 1

CRN 196314-61-1 CMF C11 H12 F6 O

CM 2

CRN 154970-45-3 CMF C12 H18 O2

CM 3

CRN 585-07-9 CMF C8 H14 O2

CM 5

CRN 108-31-6 CMF C4 H2 O3